

### PNP -1.5A -30V Middle Power Transistor

Parameter	Value
$V_{\sf CEO}$	-30V
I <sub>C</sub>	−1.5A

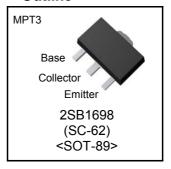
#### Features

- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SD2662
- 3) Low  $V_{\text{CE(sat)}}$

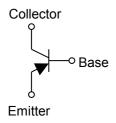
$$V_{CE(sat)} = -0.37V(Max.)$$
  
 $(I_C/I_B = -1A/-50mA)$ 

4) Lead Free/RoHS Compliant.

#### Outline



#### •Inner circuit



# Applications

Motor driver , LED driver Power supply

### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SB1698	MPT3	4540	T100	180	12	1,000	FL



# ●Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V <sub>CBO</sub>	-30	V
Collector-emitter voltage		V <sub>CEO</sub>	-30	V
Emitter-base voltage		$V_{EBO}$	V <sub>EBO</sub> –6	
Collector current	DC	I <sub>C</sub>	<b>–1.5</b>	Α
	Pulsed	I <sub>CP</sub> *1	-3	А
Power dissipation		P <sub>D</sub> *2	0.5	W
		P <sub>D</sub> *3	2.0	W
Junction temperature		T <sub>j</sub>	150	°C
Range of storage temperature		T <sub>stg</sub>	−55 to +150	°C

<sup>\*1</sup> Pw=1ms, single pulse

## ●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	$I_C = -1mA$	-30		-	V
Collector-base breakdown voltage	BV <sub>CBO</sub>	I <sub>C</sub> = -10μA	-30	1	-	V
Emitter-base breakdown voltage	BV <sub>EBO</sub>	I <sub>E</sub> = -10μA	<del>-</del> 6	ı	-	٧
Collector cut-off current	I <sub>OBO</sub>	$V_{CB} = -30V$	-	-	-100	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -6V	-	-	-100	nA
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = -1A$ , $I_B = -50 \text{mA}$	ı	-200	-370	mV
DC current gain	h <sub>FE</sub>	$V_{CE} = -2V, I_{C} = -100 \text{mA}$	270	-	680	-
Transition frequency	f <sub>T</sub>	$V_{CE} = -2V$ , $I_E = 100$ mA f=100MH <sub>Z</sub>	ı	280	-	MHz
Output capacitance	$C_{\sf ob}$	$V_{CB} = -10V$ , $I_E = 0A$ f = 1MHz	-	13	-	pF

<sup>\*2</sup> Each terminal mounted on a reference land

<sup>\*3</sup> Mounted on a ceramic board (40×40×0.7 mm)

### ●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

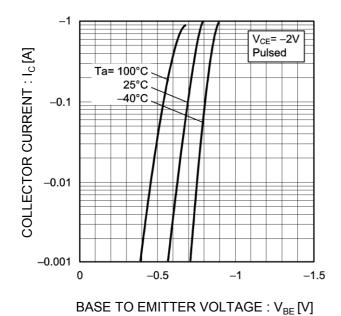


Fig.2 Typical Output Characteristics

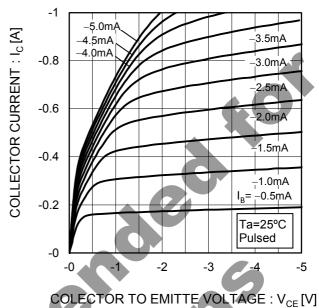


Fig.3 DC Current Gain vs. Collector Current(I)

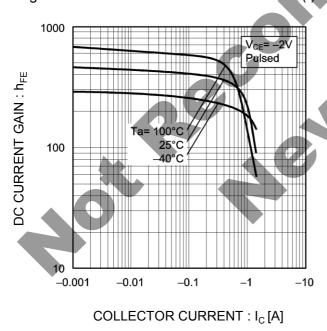
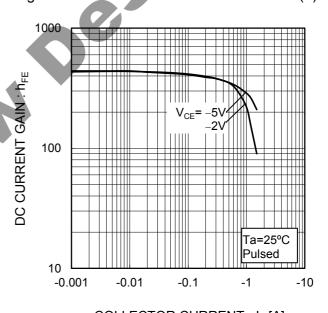


Fig.4 DC Current Gain vs. Collector Current(II)



#### ●Electrical characteristic curves(Ta = 25°C)

Fig.5 Collector-Emitter Saturation Voltage

VS. Collector Current (I)

-1

VOLTAGE

NON VOLTAGE

Ta= 100°C

25°C

-40°C

-0.01

-0.001

-0.001

-0.001

-0.01

-0.1

-0.01

-0.1

-0.1

-0.01

-0.1

-0.1

-0.1

-0.1

-0.1

-0.1

-0.1

-0.1

-0.1

-0.1

-0.1

-0.1

-0.1

-0.1

COLLECTOR CURRENT : I<sub>C</sub>[A]

Fig.6 Collector-Emitter Saturation Voltage
vs. Collector Current (II)

Ta= 25°C
Pulsed

-0.01

-0.01

-0.001

-0.001

COLLECTOR CURRENT: 1<sub>C</sub> [A]

Fig.7 Base-Emitter Saturation Voltage
vs. Collector Current

Ta=-40°C
25°C
100°C
1c/I<sub>B</sub>=20/1

COLLECTOR CURRENT: I<sub>C</sub> [A]

Fig.8 Gain Bandwidth Product
vs. Emitter Current

Ta= 25°C
Vc= -2V
f=100MHz
Pulsed

100
0.001
0.1
1
10
EMITTER CURRENT: I<sub>E</sub> [A]

COLLECTOR OUTPUT CAPACITANCE: Cob [pF]

EMITTER INPUT CAPACITANCE: Cib [pF]

10

-0.1

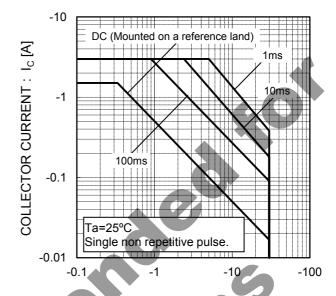
### ●Electrical characteristic curves(Ta = 25°C)

Fig.9 Emitter input capacitance vs. **Emitter-Base Voltage** Collector output capacitance vs. Collector-Base Voltage 1000 Ta= 25°C f=1MHz I<sub>C</sub>=0A  $C_{ib}$ 100

COLLECTOR - BASE VOLTAGE : V<sub>CB</sub> [V] EMITTER - BASE VOLTAGE : VEB [V]

-100

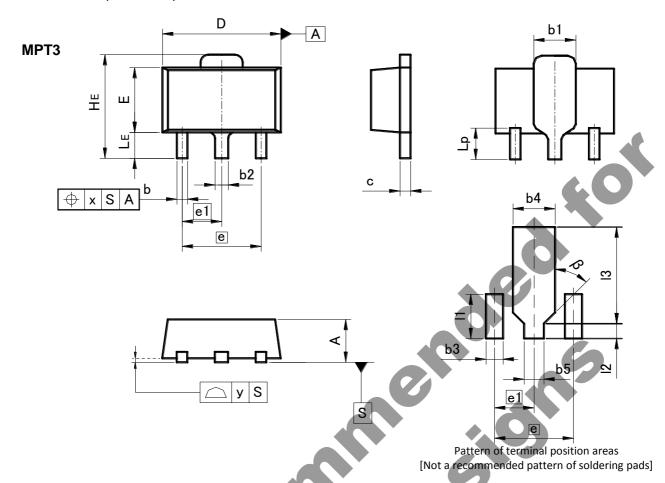
Fig. 10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE: V<sub>CE</sub> [V]



## ●Dimensions (Unit : mm)



DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
С	0.35	0.50	0.014	0.020	
D D	4.40	4.70	0.173	0.185	
E	2.40	2.70	0.094	0.106	
е	3.0	00	0.1	18	
e1	1.	50	0.059		
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
х		0.15	_	0.006	
У	-	0.10	_	0.004	

DIM	MILIMI	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
b3	-	0.65	-	0.026	
b4	-	1.70	-	0.067	
b5	-	0.75	-	0.030	
11	1	1.71	-	0.067	
12	ı	0.58	1	0.023	
13	-	3.72	_	0.146	
β	45°		45°		

Dimension in mm / inches

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